NSN 5961-01-332-8082

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View Online at https://aerobasegroup.com/nsn/5961-01-332-8082 **Inclosure Material:** Metal **Overall Length:** Between 0.747 inches and 0.915 inches **Terminal Length:** Between 0.315 inches and 0.415 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-61 **Mounting Method:** Terminal and threaded stud **Features Provided:** Hermetically sealed case and electrostatic sensitive **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 100.0 breakdown voltage, dc and 20.0 gate to source voltage **Current Rating Per Characteristic:** 30.00 amperes drain current and 120.00 amperes off-state current, peak **Power Rating Per Characteristic:** 150.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

No Fiig:

A110a0

Demilitarization: